

1. General description

Planar passivated Silicon Controlled Rectifier (SCR) in a SOT404 (D2PAK) surface mountable plastic package intended for use in applications requiring very high inrush current capability, high thermal cycling performance and high junction temperature capability ($T_{j(max)} = 150$ °C).

2. Features and benefits

- High bidirectional blocking voltage capability
- · High junction operating temperature capability
- High thermal cycling performance
- · Planar passivated for voltage ruggedness and reliability
- Surface mountable package
- Very high current surge capability

3. Applications

- Capacitive Discharge Ignition (CDI)
- Crowbar protection
- Inrush protection
- Motor control
- Voltage regulation

4. Quick reference data

able 1. Quick	reference data				,		
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{RRM}	repetitive peak reverse voltage			-	-	600	V
I _{T(AV)}	average on-state current	half sine wave; T _{mb} ≤ 129 °C; <u>Fig. 1</u>		-	-	12.7	А
I _{T(RMS)}	RMS on-state current	half sine wave; T _{mb} ≤ 129 °C; <u>Fig. 2;</u> <u>Fig. 3</u>		-	-	20	A
I _{TSM}	non-repetitive peak on- state current	half sine wave; T _{j(init)} = 25 °C; t _p = 10 ms; <u>Fig. 4; Fig. 5</u>		-	-	210	A
		half sine wave; T _{j(init)} = 25 °C; t _p = 8.3 ms		-	-	231	A
Tj	junction temperature			-	-	150	°C
Static charact	teristics	·					
I _{GT}	gate trigger current	V _D = 12 V; I _T = 0.1 A; T _j = 25 °C; <u>Fig. 7</u>		-	4.5	32	mA
Dynamic chai	racteristics		I				

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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 402 V; T _j = 150 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit	1000	-	-	V/µs

5. Pinning information

Table 2.	Pinning in	formation		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	К	cathode	mb	A - D K
2	А	anode		G sym037
3	G	gate		symosi
mb	A	mounting base; connected to anode		
			D2PAK (SOT404)	

6. Ordering information

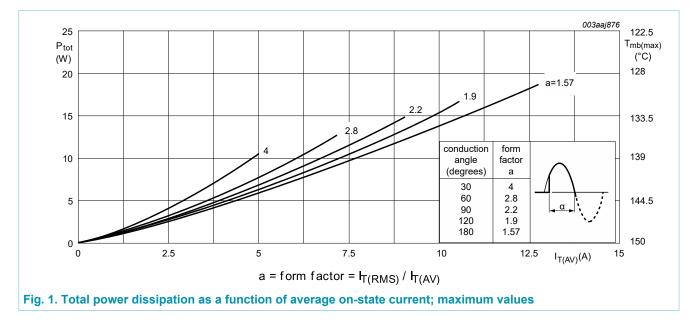
Table 3. Ordering i	nformation		
Type number	Package		
	Name	Description	Version
TYN20B-600T	D2PAK	plastic single-ended surface-mounted package (D2PAK); 3 leads (one lead cropped)	SOT404

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{DRM}	repetitive peak off-state voltage		-	600	V
V _{RRM}	repetitive peak reverse voltage		-	600	V
I _{T(AV)}	average on-state current	half sine wave; T _{mb} ≤ 129 °C; <u>Fig. 1</u>	-	12.7	А
I _{T(RMS)}	RMS on-state current	half sine wave; T _{mb} ≤ 129 °C; <u>Fig. 2;</u> <u>Fig. 3</u>	-	20	A
I _{TSM}	non-repetitive peak on- state current	half sine wave; $T_{j(init)}$ = 25 °C; t_p = 10 ms; Fig. 4; Fig. 5	-	210	A
		half sine wave; T _{j(init)} = 25 °C; t _p = 8.3 ms	-	231	А
l ² t	I ² t for fusing	t _p = 10 ms; sine-wave pulse	-	220.5	A²s
dl _T /dt	rate of rise of on-state current	I _G = 70 mA	-	100	A/µs
I _{GM}	peak gate current		-	5	А
V _{RGM}	peak reverse gate voltage		-	5	V
P _{GM}	peak gate power		-	20	W
P _{G(AV)}	average gate power	over any 20 ms period	-	1	W
T _{stg}	storage temperature		-40	150	°C
Tj	junction temperature		-	150	°C

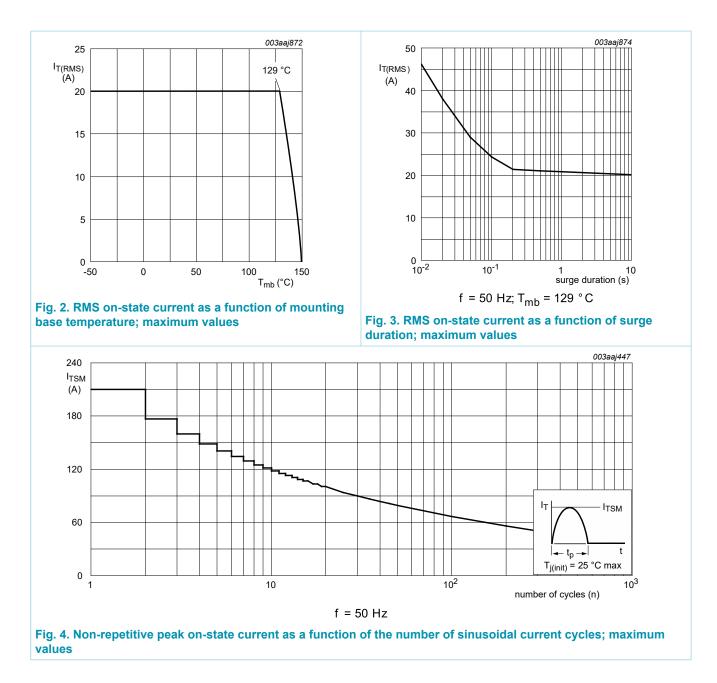


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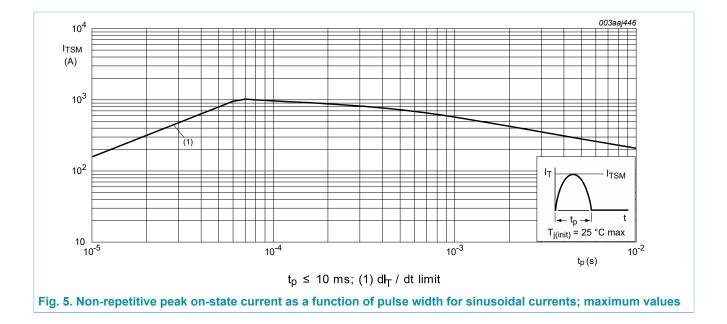
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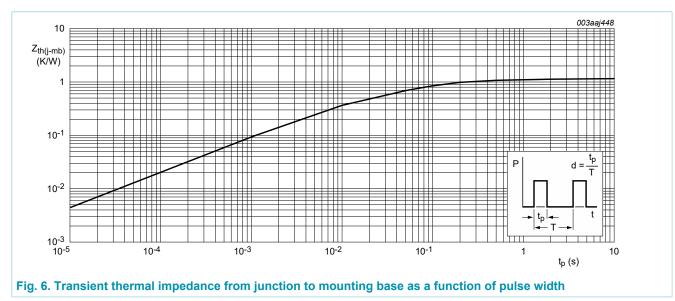
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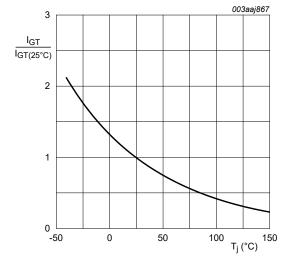
8. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-mb)}	thermal resistance from junction to mounting base	<u>Fig. 6</u>	-	-	1.1	K/W
R _{th(j-a)}	thermal resistance from junction to ambient free air	minimum footprint, FR4 board	-	55	-	K/W



9. Characteristics

Table 6. Char	racteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	cteristics					
I _{GT}	gate trigger current	V _D = 12 V; I _T = 0.1 A; T _j = 25 °C; <u>Fig. 7</u>	-	4.5	32	mA
IL	latching current	V _D = 12 V; I _G = 0.1 A; T _j = 25 °C; <u>Fig. 8</u>	-	21	60	mA
I _H	holding current	V _D = 12 V; T _j = 25 °C; <u>Fig. 9</u>	-	16	40	mA
V _T	on-state voltage	I _T = 32 A; T _j = 25 °C; <u>Fig. 10</u>	-	1.2	1.5	V
V _{GT}	gate trigger voltage	V _D = 12 V; I _T = 0.1 A; T _j = 25 °C; Fig. 11	-	0.7	1.3	V
		V _D = 400 V; I _T = 0.1 A; T _j = 150 °C; Fig. 11	0.2	0.4	-	V
I _D	off-state current	V _D = 600 V; T _j = 150 °C	-	0.2	1	mA
I _R	reverse current	V _R = 600 V; T _j = 150 °C	-	0.2	1	mA
Dynamic cha	aracteristics		 			
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 402 V; T _j = 150 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit	1000	-	-	V/µs



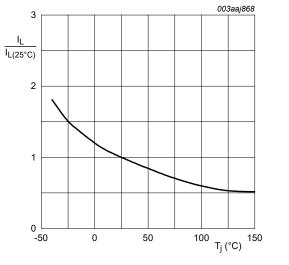
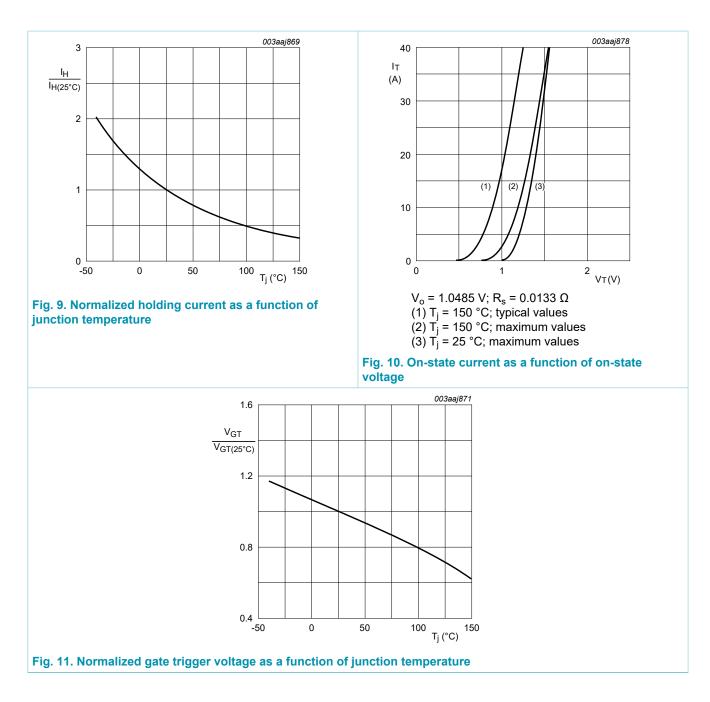


Fig. 7. Normalized gate trigger current as a function of
junction temperatureFig. 8. Normalized latching current as a function of
junction temperature

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10. Package outline

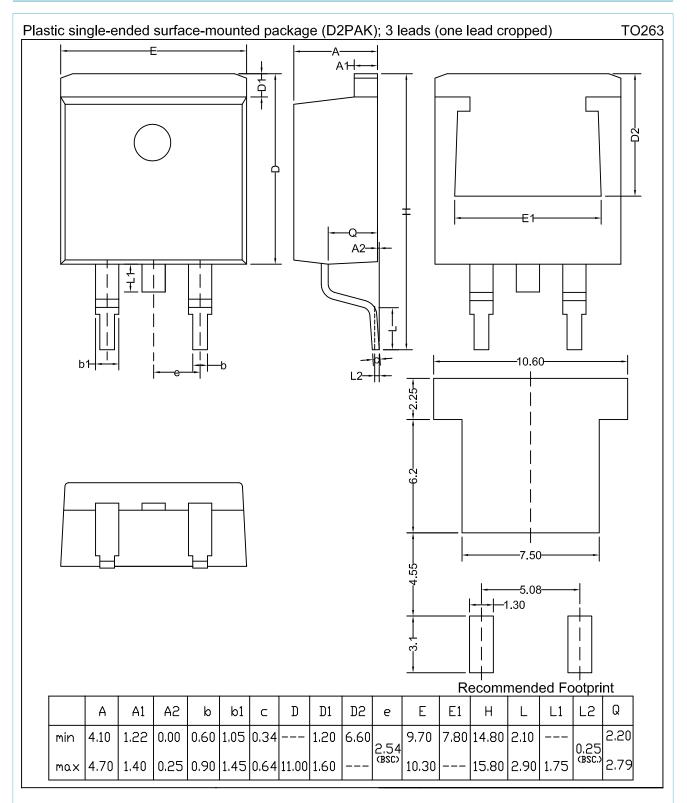


Fig. 12. Package outline D2PAK (SOT404)

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Data sheet status

Document status [1][2]	Product status [<u>3]</u>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
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